# NSR0320MW2T1

# **Schottky Barrier Diodes**

These Schottky barrier diodes are designed for high current, handling capability, and low forward voltage performance.

## Features

- Low Forward Voltage 0.24 Volts (Typ) @  $I_F = 10 \text{ mAdc}$
- High Current Capability
- ESD Rating Human Body Model: CLASS 3B – Machine Model: C
- Pb–Free Packages are Available

### **MAXIMUM RATINGS** ( $T_J = 125^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	20	Vdc
Peak Revese Voltage	V <sub>RM</sub>	23	V
Forward Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>F</sub>	200 2.0	mW mW/°C
Forward Current (DC) Continuous	١ <sub>F</sub>	1	A
Forward Current t = 8.3 ms Half Sinewave	١ <sub>F</sub>	5	A
Junction Temperature	TJ	125 Max	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

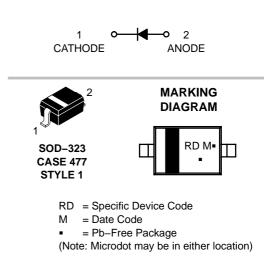
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



# **ON Semiconductor®**

http://onsemi.com

# HIGH CURRENT SCHOTTKY BARRIER DIODE



### **ORDERING INFORMATION**

Device	Package	Shipping†
NSR0320MW2T1	SOD-323	3000/Tape & Reel
NSR0320MW2T1G	SOD-323 (Pb-Free)	
NSR0320MW2T3G	SOD-323 (Pb-Free)	10,000/Tape & Reel

<sup>+</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Total Capacitance (V <sub>R</sub> = 5.0 V, f = 1.0 MHz)		-	25	29	pF
Reverse Leakage (V <sub>R</sub> = 15 V)	I <sub>R</sub>	-	10	50	μAdc
Reverse Leakage ( $V_R$ = 2.0 V @ 85° C)	I <sub>R</sub>	-	200	300	μΑ
Reverse Leakage (V <sub>R</sub> = 15.0 V @ $85^{\circ}$ C)	I <sub>R</sub>	-	450	1000	μΑ
Forward Voltage (I <sub>F</sub> = 10 mAdc)	V <sub>F</sub>	-	0.24	0.27	Vdc
Forward Voltage (I <sub>F</sub> = 100 mAdc)	V <sub>F</sub>	-	0.30	0.35	Vdc
Forward Voltage (I <sub>F</sub> = 900 mAdc)	V <sub>F</sub>	-	0.45	0.50	Vdc

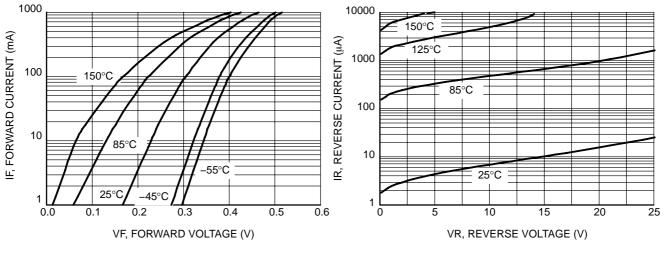


Figure 1. Forward Voltage

Figure 2. Leakage Current

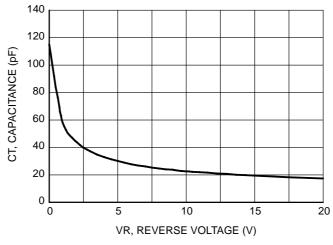
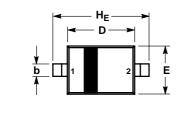
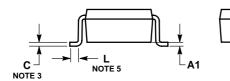


Figure 3. Total Capacitance

## PACKAGE DIMENSIONS

SOD-323 CASE 477-02 ISSUE G





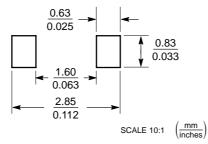
- NOTES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETERS.
  LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
  DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
С	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
Е	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105

STYLE 1: PIN 1. CATHODE 2. ANODE

# SOLDERING FOOTPRINT\*

⊢A3



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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